

# RLS244

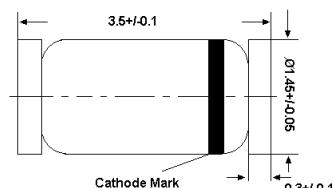
## Silicon Epitaxial Planar Diode

High Voltage Switching Diode

### Features

- Glass sealed envelope
- High reliability

LL-34



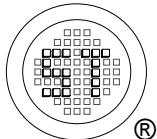
Glass case MiniMELF  
Dimensions in mm

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Peak Reverse Voltage	$V_{RM}$	250	V
DC Reverse Voltage	$V_R$	220	V
Average Forward Current	$I_{F(AV)}$	200	mA
Peak Forward Current	$I_{FM}$	625	mA
Surge Forward Current (1 s)	$I_{FSM}$	1000	mA
Power Dissipation	$P_{tot}$	300	mW
Junction Temperature	$T_j$	175	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 65 to + 175	$^\circ\text{C}$

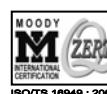
### Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 200 \text{ mA}$	$V_F$	1.5	V
Reverse Current at $V_R = 220 \text{ V}$	$I_R$	10	$\mu\text{A}$
Capacitance between Terminals at $V_R = 0$ , $f = 1 \text{ MHz}$	$C_T$	3	pF
Reverse Recovery Time at $I_F = 20 \text{ mA}$ , $I_R = 20 \text{ mA}$ , $R_L = 50 \Omega$	$t_{rr}$	75	ns



**SEMTECH ELECTRONICS LTD.**

(Subsidiary of Sino-Tech International Holdings Limited, a company listed on the Hong Kong Stock Exchange, Stock Code: 724)



ISO/TIS 16949 : 2002

ISO 14001:2000

ISO 9001:2000

BS-OHSAS 18001:2007

IECQ QC 080000

Certificate No. 05103

Certificate No. 7116

Certificate No. 050908

Certificate No. 7116

Certificate No. RGH-0001

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